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Understanding of copolymers containing pyridine and selenophene simultaneously and their polarity conversion in transistors†

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By simultaneously considering the powerful electron-accepting capability of pyridine and the strong selenophene (Se)–Se interaction of selenophene, we present here the design and synthesis of both pyridine and selenophene-containing, pyridine-flanked diketopyrrolopyrrole and 4,7-di(selenophen-2-yl)-2,1,3-benzothiadiazole-based copolymers (P1 and P2) for use in organic field-effect transistors, where P1 has a shorter branched position of the side chains in relation to the backbone as compared to P2. The structure–property relationships associated with branching point engineering in the copolymers are established by applying a range of technical analyses. Overall, P1 interestingly exhibits both a higher hole and electron mobility of up to $1.2 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ and $0.21 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, respectively, which are over one order of magnitude higher than that of P2. This observation demonstrates the opposite view of the branching points away from the backbone for high-performing organic field-effect transistors. Besides, by doping sodium bicarbonate and molybdenum trioxide with electrodes, we succeeded in affecting the transition from ambipolarity of P1 to unipolar n- and p-type characteristics, respectively. These findings improve our understanding of both the role of branching point engineering in enhancing the carrier transport and the use of doping for switching the polarity of P1.

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Introduction

Owing to their superiority in cost-effective, large-area, and mechanically flexible electronics, solution processable organic field-effect transistors (OFETs) based on π -conjugated semiconducting polymers have been extensively studied in recent years.^{1–9} Enormous efforts have been made to develop high-performance polymers comprising electron-donor and electron-acceptor units (so-called D–A-type structures). This has resulted in achieving charge-carrier mobility higher than that of amorphous silicon,^{10–19} even being comparable with the performance of vacuum-deposited small molecule and organic single-crystal OFETs.^{20–27}

Centrosymmetric polar bicyclic lactam structures, such as diketopyrrolopyrrole (DPP), isoindigo, and thienoisindigo,

are very promising building units, which can construct state-of-the-art semiconducting polymers with excellent charge transport characteristics because of the following reasons. (i) A superior coplanarity, which extends the effective conjugation length, (ii) a strong tendency to form π – π stacks with large overlapping areas, and (iii) a quinoid structure, which enhances the charge delocalization, all of which can induce higher-order molecular organization, and thus, facilitate efficient charge transport.^{10,11,15,16,20,24,25,28–37}

When pyridine units serve as adjacent flankers in the DPP core, the so-called pyridine-flanked DPP (PyDPP) is accompanied by beneficial features. The nitrogen atoms of the pyridine in the PyDPP unit not only create a fully coplanar geometry, which maximizes strong intermolecular π – π interactions, but PyDPP also possesses a stronger electron-accepting ability, which strengthens the intramolecular charge transport (ICT) through a strong D–A interaction and provides deeper lowest unoccupied molecular orbital (LUMO) levels compared to that of DPP polymers flanked with two five-membered rings, facilitating a better electron transport through the polymer backbone and more efficient electron injection between the gold (Au) electrode and polymer semiconductors.^{38–45} On the other hand, introducing selenophene (Se) units as a subunit into the conjugated backbone can boast strong Se–Se and π – π

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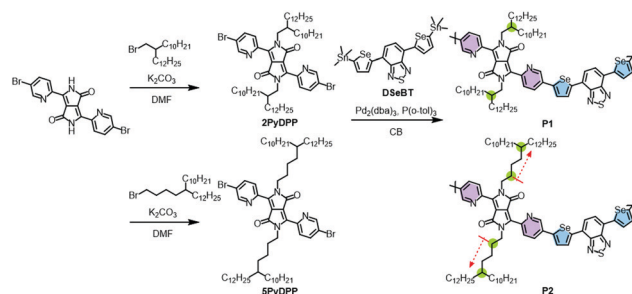
interactions between neighboring chains, which assists in the enhancement of crystallization, organization, and interchain carrier transport. Besides, a larger and more polarizable radius of selenophene over thiophene can facilitate the orbital overlap as well as intermolecular interaction.^{46–50}

Therefore, a design strategy that merges the advantages afforded by both pyridine and selenophene units is worthy of investigation. However, the strong electron donating properties of selenophene may result in higher frontier energy levels (the highest occupied molecular orbital (HOMO) and LUMO) of the polymers, sacrificing an efficient electron transport. A benzothiadiazole unit can be adopted as a weak acceptor to tune the HOMO/LUMO levels of Se-containing polymers and simultaneously enhance the ICT through the backbone. This paper reports the synthesis and characterization of copolymers containing PyDPP and 4,7-di(selenophen-2-yl)-2,1,3-benzothiadiazole (**DSeBT**) units simultaneously for OFET applications. Recent reports have indicated that selecting the side chains is as important as selecting the conjugated backbones when designing conjugated polymers. Therefore, with the additional aim of investigating the effects of the branching points of the side chains on **PyDPP–DSeBT**-based copolymers, the decyltetradecyl (a short branched version) and 5-decylheptadecyl (a long branched version) side chains are introduced into the backbone, affording P1 and P2, respectively. Both copolymers display ambipolar transport property in OFETs and P1 exhibits higher hole and electron mobilities of $1.2 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ and $0.21 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, respectively, which are over one order of magnitude greater than those of P2. In fact, the observed higher mobility for P1 is in contrast to the previously demonstrated better OFET performance of polymers with long branched points from the backbone relative to the analogues with short branched points. The performance of P1 is compared to representative works related to PyDPP-containing or Se-containing polymers in Chart S1 and Table S1 in ESI.† Many PyDPP-containing and Se-containing polymers show unipolar characteristics and low charge mobility, but P1 somewhat makes up for the weakness of PyDPP and Se by containing both units. This paper also presents a successful conversion of the ambipolar nature of OFETs based on P1 into n- and p-type unipolar characteristics by depositing simple n-type sodium bicarbonate (NaHCO_3) and p-type molybdenum trioxide (MoO_3) dopants on electrodes, respectively.

Results and discussion

Synthesis and characterization

Dibrominated PyDPP was first synthesized according to the previous literature, followed by *N*-alkylation employing 2-decyltetradecyl bromide and 5-decylheptadecyl bromide under basic conditions, to afford the monomers (**2PyDPP** and **5PyDPP**).⁵¹ The distannylated comonomer **DSeBT** was synthesized according to the reported literature.^{47,49} As depicted in Scheme 1, the PyDPP-based target copolymers (P1 and P2) were synthesized by a palladium-catalyzed Stille polymerization of the dibrominated **2PyDPP** or **5PyDPP** with **DSeBT**. The copolymers, visible as a



Scheme 1 Synthetic routes and chemical structures of the polymers.

dark blue powder, were washed with hot methanol, acetone, and hexane and extracted using chloroform in a Soxhlet extractor, to remove the catalytic residues and oligomer mixtures. Stille polymerization at a reaction temperature of 120°C for a reaction time of 72 h provided the desirable P1 copolymer with a high yield (72%). In the case of the P2 copolymer, gelation occurred during the initial stage of polymerization at the same temperature. Thus, we applied a decreased temperature (100°C) and reaction time (5 h), resulting in a desirable, chloroform-soluble P2 copolymer. Their synthetic details are provided in the Experimental section. Both copolymers exhibited good solubility in common organic solvents, including chloroform, chlorobenzene (CB), and dichlorobenzene. Note that, relative to P1, P2 showed less solubility in the solvents, evidencing the strong solid-state packing behavior of the polymer chains. The solubility test quantified using the absorption spectra and calibration plots proved that P1 exhibited better solubility (5.80 mg mL^{-1}) than P2 (2.24 mg mL^{-1}) (Fig. S4 and Table S2, ESI†). The molecular weight (M_n) and polydispersity index (PDI) of the copolymers were determined using high-temperature gel permeation chromatography at 100°C , with 1,2,4-trichlorobenzene used as an eluent; the results are summarized in Table 1. P1 shows a higher M_n of 44.8 kDa and PDI of 2.87 compared to those of P2 ($M_n = 16.6 \text{ kDa}$ and $\text{PDI} = 2.04$), which is considered to be a result of the reduced polymerization temperature and time for preventing gelation.

Photophysical and electrochemical properties and simulation

The absorption spectra of the copolymers in CB solutions and in thin films spin-cast from CB solutions were measured using ultraviolet-visible spectroscopy (Fig. 1). The relevant data are summarized in Table 1. As shown in Fig. 1a, both polymers exhibited distinct dual-band spectra in both solution and film states.

Table 1 Photophysical and electrochemical properties of the polymers

	$\lambda_{\text{sol}}^{\text{max}}$ [nm]	$\lambda_{\text{film}}^{\text{max}}$ [nm]	λ_{onset} [nm]	$E_g^{\text{opt } a}$ [eV]	E_{HOMO}^b [eV]	E_{LUMO}^b [eV]	M_n [kDa]	PDI
P1	722	724	778	1.59	−5.80	−3.72	44.8	2.87
P2	714	718	767	1.62	−6.05	−3.75	16.6	2.04

^a Calculated from the absorption band edge of the polymer film, $E_g^{\text{opt}} = 1240/\lambda_{\text{edge}}^{\text{film}}$. ^b Thin films in *n*-Bu₄NPF₆/CH₃CN versus ferrocene/ferrocenium at 100 mV s^{-1} . HOMO and LUMO were estimated from the onset oxidation and reduction potentials, respectively, assuming the absolute energy level of ferrocene/ferrocenium to be 4.8 eV below the vacuum level.

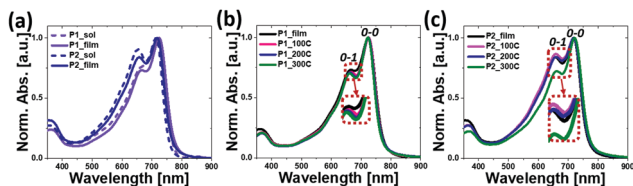


Fig. 1 Photophysical properties of the polymers.

The weak high-energy absorption bands in the 350–400 nm region corresponded to the localized π - π^* transitions, while the strong low-energy absorption bands in the 450–800 nm region were attributed to the ICT bands. The absorption maxima (λ_{max}) of P1 and P2 in solution state were 722 nm and 714 nm, respectively, and there was a negligible change in the λ_{max} and absorption onset (λ_{onset}) values when each polymer was solidified from solution to film. An analysis of the spectra revealed that the intensity of the 0–0 vibrational transition relative to the 0–1 transition increased in P1 compared to P2, and the 0–0 transition was further intensified in the film state, suggesting an enhanced π - π stacking between the polymer backbones. Furthermore, the thermal annealing of films (at 100 °C, 200 °C, and 300 °C) led to a further slight increase in the relative intensity of the 0–0 to 0–1 transition, indicating more intensified packing structures upon the annealing treatment (Fig. 1b and c).^{52–54}

Both λ_{max} and λ_{onset} values of P1 displayed a small red shift when compared to those of P2, resulting in relatively low optical bandgaps ($E_{\text{g}}^{\text{opt}}$) of 1.59 eV for P1, compared to 1.62 eV for P2, which were calculated from the onset of their film spectra. This trend is opposed to the observation recorded involving polymers with varying branched positions of the alkyl side chains, where the absorption spectra red-shifted by moving the branching points away from the backbone, as a result of a reduced steric hindrance between the polymer chains. The unexpected phenomenon currently lacks a logical explanation, but can be attributed, in part, to the different aggregation types and levels of copolymer backbones as a function of the chain branching position dynamics.^{52,55,56}

Cyclic voltammetry was performed to investigate the electrochemical behavior of the copolymer films in tetra-*n*-butylammonium hexafluorophosphate (*n*-Bu₄NPF₆)/acetonitrile (CH₃CN) solution. Both copolymers exhibited oxidation and reduction peaks during the positive and negative scans (Fig. S5, ESI†). The HOMO and LUMO energy levels were calculated from the oxidative and reductive onset potentials. As listed in Table 1, the HOMO and LUMO energy levels were –5.80 eV and –3.72 eV for P1 and –6.05 eV and –3.75 eV for P2, indicating that the HOMOs, rather than the LUMOs, were influenced by tuning the alkyl chain branching point significantly. Note that the observed deep-lying LUMO values of both P1 and P2, even deeper than those of many thiophene-flanked DPP copolymers,^{10,29,32,33,57} are considered to facilitate electron injection and transport in OFETs.^{21,38–40,44} In addition, relative to P2, the enhanced hole transport of P1 is anticipated because the deeper-lying HOMOs of P2 over P1 can lead to large hole injection barriers.^{58–61}

Density functional theory computation at the B3LYP/6-31G* level was performed on the trimeric models of the copolymers' repeating units, to obtain additional insights into their electronic distributions and geometry-optimized structures. To reduce the calculation burden, the long branched alkyl chains in the PyDPP unit were simplified to the corresponding shorter versions whilst maintaining the distance of the branching points from the backbones, that is, replacing 2-decyltetradecyl and 5-decylheptadecyl groups with 2-butylhexyl and 5-butylononyl, respectively, where the 2-butylhexyl- and 5-butylononyl-containing trimers (T1 and T2) are regarded as P1 and P2, respectively. As shown in Fig. 2, the HOMO densities were delocalized along all backbones, while their LUMO densities were relatively centralized on the electron-accepting benzothiadiazole PyDPP units. Both models showed a high structural coplanarity with very low torsional angles ($\phi < 5^\circ$) between the sub-building blocks. The dipole moments of the models were also calculated. These are depicted as red arrows in Fig. 2 and the relevant values are listed in Table S3 (ESI†). The net dipole moments of T1 and T2 were calculated as 4.42 D and 4.50 D, respectively. These simulation data imply that varying the length of the branching points only slightly affected the electron density distribution, planarity, and polarity of the copolymers.

Thin-film microstructural analyses

The film morphology and microstructures, such as topography, crystallinity, and molecular orientation of the copolymers, were analyzed using atomic force microscopy (AFM), X-ray diffraction (XRD), and two-dimensional grazing incidence X-ray diffraction (2D-GIXD) to understand the structure–property relationships associated with the length of the branching points. The copolymer films were prepared on silicon dioxide (SiO₂) substrates under the same conditions as those of the OFET device fabrication in the next section. Compared to P2, P1 showed a superior film-forming property by the spin-coating process, most likely due to its excellent solubility. Fig. 3 presents the AFM images of the copolymer films annealed at 100 °C, 200 °C, and 300 °C. All annealed P1 films showed similar smooth interfaces and small grains with an almost constant root-mean-square roughness value ($R_{\text{rms}} = \sim 1.7$ nm), regardless of the annealing temperature, whereas the surfaces and R_{rms} values of P2 showed

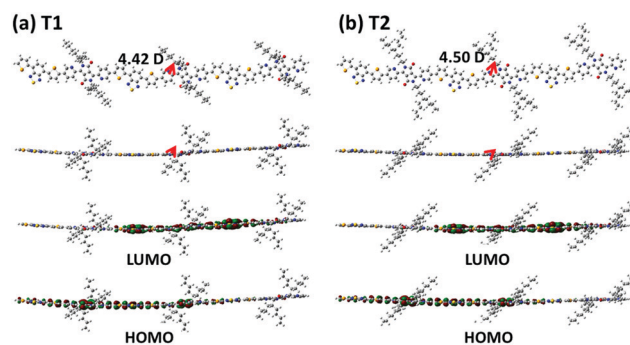


Fig. 2 DFT calculation results: illustration of dipole moments on the energy-minimized structures (top) and charge-density isosurfaces for the model system (bottom) of the trimeric units.

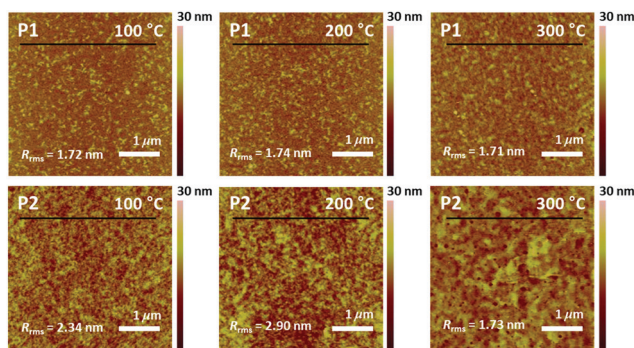


Fig. 3 AFM topography images ($5 \times 5 \mu\text{m}$) of annealed polymer films on SiO_2 substrates.

a strong dependence on the annealing temperature (R_{rms} of 2.34 (100 °C), 2.90 (200 °C), and 1.73 nm (300 °C)). The rough surface of the large grains would be of benefit to establish efficient charge transport pathways but might cause an adverse effect on the interconnectivity between the semiconductor active layer and polymethylmethacrylate (PMMA) dielectric layer used in OFETs.⁶²

Relative vertical distances of the cross section in the AFM images are also plotted in Fig. 4. All annealed P1 films showed smaller variation in the vertical distances in a given region compared to the corresponding annealed P2 cases, consistent with the observed R_{rms} trend. Note that, despite its very smooth surface, the P1 film, which was annealed at 300 °C, revealed some protruding peaks in the vertical distance plots, indicating the evolution of some agglomerations of the copolymer chains. Such agglomerated spots were further evidenced from the phase images of the films with 300 °C annealing (Fig. S6, ESI†).

Fig. 5 and 6 show the 2D-GIXD images and one-dimensional line cuts along the in-plane (q_{xy}) and out-of-plane (q_z) directions, and the calculated crystallographic parameters are listed in Table S5 (ESI†). All copolymer films annealed at 100 °C, 200 °C, and 300 °C exhibited well-defined multiple lamellar ($h00$) Bragg peaks in the out-of-plane direction and strong (010) π - π stacking peaks in the in-plane direction, indicating the formation of highly ordered lamellar and π - π stacking structures with an edge-on dominant orientation relative to the substrate. Note that despite the similarity of the diffraction

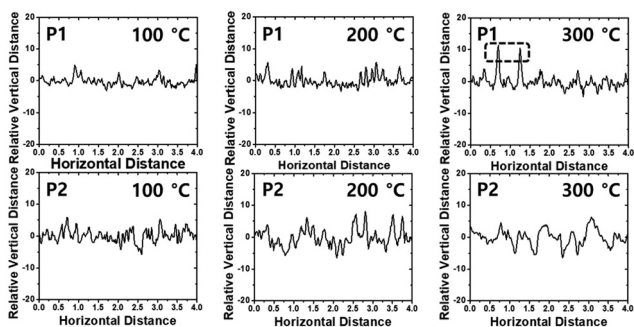


Fig. 4 Relative vertical distance plots of the cross-section in the region indicated as black lines in AFM topography images.

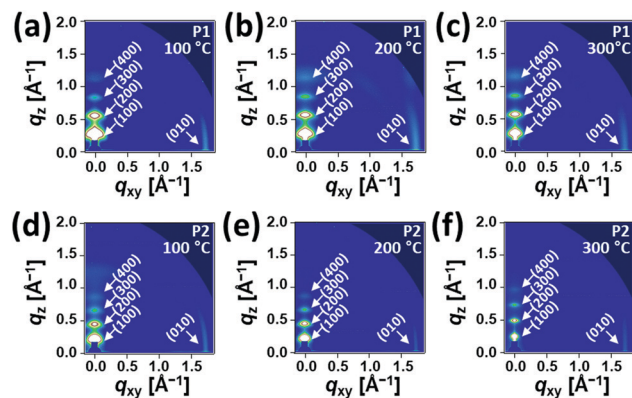


Fig. 5 2D-GIXD images of (a-c) P1 and (d-f) P2 films fabricated by the spin-casting method under different annealing conditions.

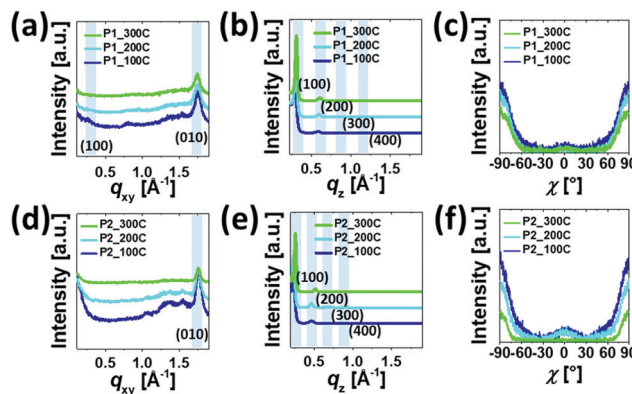


Fig. 6 1D-GIXD profiles of polymer films along (a and d) in-plane and (b and e) out-of-plane orientations under different annealing conditions. (c and f) Pole figures for π - π stacking of the polymer films. The profiles at $\chi = 0^\circ$ represent the peak intensity along the q_z direction, and those at $\chi = -90^\circ$ and $\chi = 90^\circ$ represent the peak intensity along the q_{xy} direction.

patterns of the films annealed at 100 °C, 200 °C, and 300 °C, the diffraction peaks became more distinctive and their intensities became stronger, which is further evidenced by the XRD data in Fig. S7 (ESI†). The annealed P1 films exhibited shorter lamellar d -spacing distances (20.77–22.15 Å) than those of the corresponding P2 films (24.09–27.18 Å), which is further evident from the values obtained from the XRD measurement (Table S4, ESI†), whereas π - π stacking distances showed an opposite trend (~ 3.61 Å for P1 and ~ 3.58 Å for P2). This observation suggests that moving the branching point of the side chains away from the backbone made them less interdigitated in the crystalline phase but led to a slightly closer π - π intermolecular interaction between the conjugated chains. Note that the lamellar d -spacing distances were significantly sensitive to the applied annealing temperature in comparison with the π - π stacking structures. The crystalline correlation lengths (L_c) of (010) peaks were also calculated using a Scherrer equation. Besides the observation of larger L_c values with increasing annealing temperature, the L_c values of the annealed P2 films were greater than those of the corresponding annealed P1 films, suggesting that P2 forms a larger crystalline size relative to P1, which concurs with the AFM data above.

Table 2 Crystalline population ratios obtained from the pole figures in Fig. 6

Polymer film	Temperature [°C]	π - π stacking orientation ratio [%]	
		Edge-on	Face-on
P1	100	93.5	6.5
	200	94.8	5.2
	300	92.9	7.1
P2	100	89.3	10.7
	200	86.7	13.3
	300	90.2	9.8

Additionally, we conducted a pole figure analysis for the (010) peaks under different annealing conditions in order to quantify the crystalline orientation of the films, as shown in Fig. 6 and Table 2. When compared to the P2 films, the annealed P1 films exhibited higher edge-on crystallite ratios, especially for the 200 °C-annealed P1, holding the edge-on crystallite near 95%. In theory, the edge-on orientation of crystallites is a positive sign for a high charge transport property *via* the mechanism of an effective intermolecular carrier hopping because of the parallel arrangement of the plane of the conjugated backbone to the current flow through the channel.^{63–65}

Electrical characterization and performance of OFETs

To study the carrier transport properties of the copolymers, top-gate/bottom-contact OFETs were fabricated on a glass substrate and measured in a glove box under nitrogen (N₂) conditions. After depositing the Au source and drain onto a glass substrate, the copolymers were spin-cast from the chlorobenzene solution (5 mg mL⁻¹ at 2000 rpm for 60 s). To investigate the thermal annealing effect on the performance of the devices, the spin-cast semiconductor layers were annealed at three different temperatures (100 °C, 200 °C, and 300 °C) for 30 min, and then cooled. A 500 nm-thick PMMA dielectric ($C_i = 6.20$ nF cm⁻²) was subsequently deposited and heated at 80 °C for 2 h, covered by an aluminium (Al) gate electrode using thermal evaporation. The detailed fabrication procedure is described in the Experimental section. All the transfer and output curves and the device parameters, including electron and hole mobility (μ_e and μ_h), threshold voltage (V_{th}), and on/off current ratio ($I_{on/off}$), are provided in Fig. 7 and Table 3, where μ_e and μ_h with $I_{on/off}$ were calculated from the transfer characteristics of the devices in the saturation regime.

All annealed copolymer films exhibited ambipolar transistor behaviors; overall, P1 OFETs exhibited higher μ_e and μ_h than P2 OFETs. This observation is in contrast to the previous reports, where the use of farther branched alkyl chains resulted in improved charge transport efficacy due to the closer π -backbone stacking.^{29,39,48} The 200 °C-annealed P1 film exhibited the highest μ_e and μ_h of 1.2 cm² V⁻¹ s⁻¹ and 0.21 cm² V⁻¹ s⁻¹, respectively, which are over one order of magnitude greater than those of the best-performing 300 °C-annealed P2 samples. All annealed P1 films revealed ambipolar transport characteristics with higher μ_e over μ_h . By contrast, for P2, the incidence of higher μ_h over μ_e was

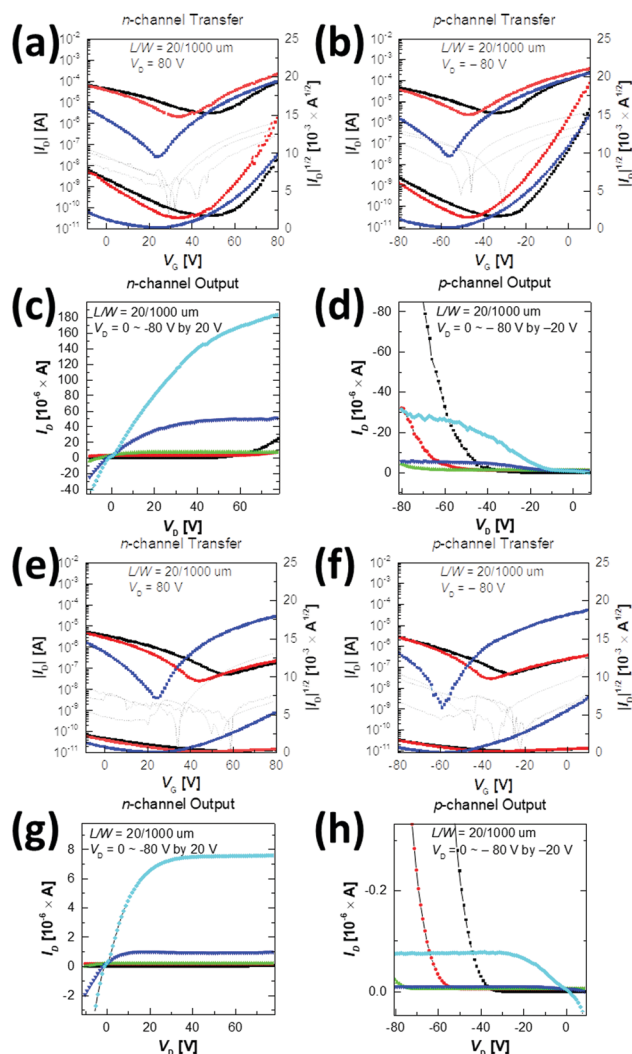


Fig. 7 (a, b, e and f) Transfer and (c, d, g and h) output characteristics of the n-type and p-type devices of (a–d) P1 and (e–h) P2 under different annealing conditions: 100 °C (black), 200 °C (red) and 300 °C (blue).

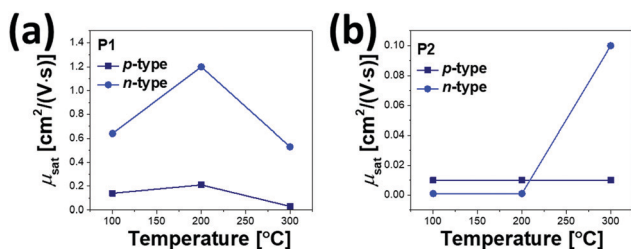
observed at annealing temperatures of 100 °C and 200 °C, while μ_e was significantly improved after annealing at 300 °C, as illustrated in Fig. 8. This resulted in the n-type dominant ambipolar transistor property, as observed in the P1 cases.

Relative to the P2 films, the highly efficient charge transport observed for the P1 films was due to the high film quality with a uniform surface, decreased lamellar d -spacing, and high edge-on crystallite ratio, as evidenced by the morphology analysis above. Note also that the P2 films exhibited constant low μ_h values of 0.01 cm² V⁻¹ s⁻¹, regardless of the different annealing temperatures, which is most likely a result of the too deep-lying HOMO level (−6.05 eV), which causes large hole injection barriers with respect to the work function of the Au electrodes ($W_f \approx 5.1$ eV). The better charge transport of P1 may come from the higher molecular weight than that of P2; thus we additionally synthesized P1 ($M_n = 16.2$ kDa and PDI = 2.35) with a similar molecular weight to P2. Although the molecular weight did affect the performance of OFETs, the newly synthesized P1

Table 3 Electrical characteristics of the polymer OFET devices under different annealing conditions

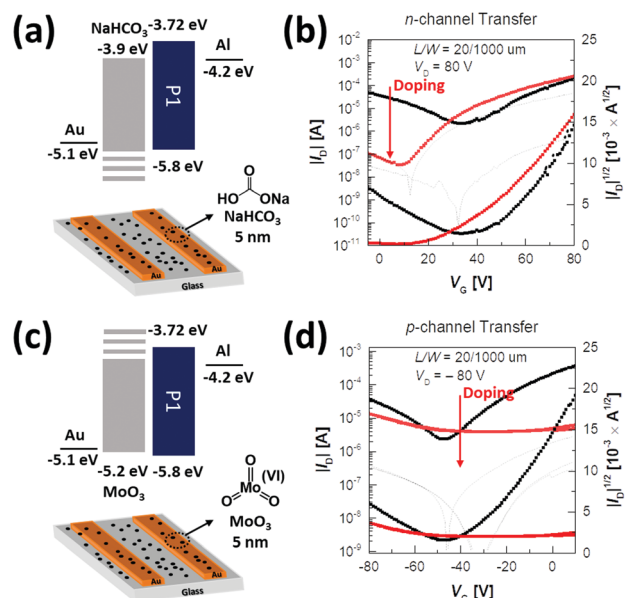
	T_a [°C]	n-channel			p-channel		
		μ_e [cm ² V ⁻¹ s ⁻¹]	V_{th} [V]	I_{on}/I_{off}	μ_e [cm ² V ⁻¹ s ⁻¹]	V_{th} [V]	I_{on}/I_{off}
P1	100	0.64 (± 0.01)	47 (± 3)	10	0.14 (± 0.01)	-34 (± 2)	10
	200	1.20 (± 0.02)	47 (± 2)	10 ²	0.21 (± 0.02)	-49 (± 2)	10 ²
	300	0.53 (± 0.07)	51 (± 5)	10 ³	0.03 (± 0.001)	-61 (± 5)	10 ³
P2	100	0.001 ($\pm 8 \times 10^{-5}$)	44 (± 0.3)	10 ²	0.01 (± 0.005)	-37 (± 6)	10
	200	0.001 ($\pm 2 \times 10^{-4}$)	34 (± 4)	10 ²	0.01 (± 0.006)	-35 (± 3)	10 ²
	300	0.10 (± 0.02)	53 (± 1)	10 ³	0.01 (± 0.01)	-51 (± 0.5)	10 ⁴

6 devices for each condition were fabricated and used for mobility calculation.

**Fig. 8** Hole and electron mobility trends of (a) P1 and (b) P2 OFET devices according to the annealing temperature.

still showed higher μ_e and μ_h compared to those of P2, as shown in Fig. S8, S9 and Table S6 (ESI[†]).

Furthermore, we attempted to modify the Au source/drain electrodes by doping NaHCO₃, in order to look into the possibility of an n-type unipolar device, which is essential for a p-n junction with a complementary device due to the defects of ambipolar devices derived from the opposing charge flows.^{66–69} For increasing the positive voltage, the hole transport in the ambipolar devices increased the off current and operated as a leakage current in electron transport. For increasing the negative voltage, the electrons acted as a barrier to the hole transport, consequently reducing the on/off characteristics of the devices and the accuracy in extracting the mobility and threshold voltage. The superior-performing P1 was selected for this study. The cost-effective NaHCO₃ as an n-type dopant deposited on the Au electrodes *via* thermal evaporation could successfully tune the energy level of the Au electrodes from -5.1 to -3.9 eV, as shown in Fig. 9a, and therefore, reduce the energy mismatch between the Au electrode and LUMO levels of the P1 copolymer. This facilitated an effective electron injection from the Au electrodes to the P1 copolymer film and hindered the hole injection from the electrodes. The transfer curves of the modified device are shown in Fig. 9b and the obtained data are given in Table 4. The 200 °C-annealed P1-based device with NaHCO₃ revealed an excellent “unipolar n-type transistor” with a high μ_e of up to 0.94 cm² V⁻¹ s⁻¹ in addition to a decreased V_{th} and increased $I_{on/off}$ value, when compared to the optimized device without NaHCO₃. We further examined the use of MoO₃ as a p-type dopant in Au electrodes, which decreased the work function to -5.2 eV, enabling the “unipolar p-type transistor” ($\mu_h = 0.04$ cm² V⁻¹ s⁻¹ with low $V_{th} = -32.3$ V and high $I_{on/off} = 10$) (Fig. 9c and d). These results demonstrate that PyDPP-DSeBT-based ambipolar semiconductors

**Fig. 9** (a and c) The energy level diagram of materials used in a modified device and the schematic illustration of doping on the device, and (b and d) the transfer characteristics of (a and b) the n-type P1 device with NaHCO₃ doping and (c and d) the p-type P1 device with MoO₃ doping under the 200 °C annealing condition.**Table 4** Electrical characteristics of the P1 OFET devices without and with NaHCO₃ and MoO₃ doping under the 200 °C annealing condition

Doping	Channel type	μ [cm ² V ⁻¹ s ⁻¹]	V_{th} [V]	I_{on}/I_{off}
Conventional	n-type	1.2	47.3	10 ²
	p-type	0.21	-49.2	10 ²
NaHCO ₃ (5 nm)	n-type	0.91	38.3	10 ³
	p-type	N/A	—	—
MoO ₃ (5 nm)	n-type	N/A	—	—
	p-type	0.04	-32.3	10

can be converted into either unipolar n-type or p-type materials by utilizing the simple doping technology.

Conclusions

We developed PyDPP-DSeBT-based alternating copolymers (P1 and P2), where P1 exhibited a shorter length of the branched position of the side chains from the backbone than P2. It was

found that tuning the branching point had an almost negligible influence on the optical properties and the calculated dipole moments of the copolymers, but directly affected their solubility, HOMO/LUMO energy levels, film surface morphology, film microstructure, and charge transport characteristics. Specifically, when compared to P2, P1 exhibited a higher solubility, smoother surface, smaller crystallites size, tighter lamellar structure, and larger edge-on crystallite ratio, accounting for superior ambipolar transport characteristics with μ_e and μ_h of $1.2 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$ and $0.21 \text{ cm}^2 \text{ V}^{-1} \text{ s}^{-1}$, respectively. These results provided differing viewpoints on the branching position control for improving the OFET performance. We also successfully demonstrated unipolar n-type and p-type OFETs obtained from the intrinsic ambipolar P1 by introducing NaHCO_3 and MoO_3 dopants into Au electrodes, respectively. Not only does this study improve our understanding of the role of the branching position of the side chains in a class of copolymers based on PyDPP and DSeBT building blocks, but it also presents a simple doping method for the main polarity conversion in OFETs. Moreover, the deep-lying HOMO/LUMO levels and the broad absorption range including the 400–800 nm wavelength region indicate a great potential of the polymers for future applications in polymer solar cells as acceptor polymers possessing great compatibility with DPP-based donor polymers.

Experimental section

Materials and characterization

3,6-Bis(5-bromopyridin-2-yl)-2,5-bis(2-decyltetradecyl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione (**2PyDPP**), 4,7-bis(5-(trimethylstannyl)selenophen-2-yl)-2,1,3-benzothiadiazole (**DSeBT**) and 5-decylheptadecyl bromide were synthesized according to the reported literature.^{38,47,49} All other chemicals and reagents were purchased from Sigma-Aldrich, Alfa Aesar Chemical Company, and Tokyo Chemical Industry Co., Ltd and used without any further purification. All solvents are ACS and anhydrous grade by distillation. ^1H NMR and ^{13}C NMR spectra were recorded on a Bruker AVANCE III HD 400 MHz spectrometer using deuterated CDCl_3 as solvent and tetramethylsilane (TMS) as an internal standard. Elementary analyses were carried out using a Flash 2000 element analyzer (Thermo Scientific, Netherlands) and MALDI-TOF MS spectra were checked by using Ultraflex III (Bruker, Germany). UV-vis-NIR absorption spectra in solution and in thin films were measured by using a UV-1800 (SHIMADZU) and Cary 5000 UV-vis-near-IR double-beam spectrophotometer. The number-average (M_n) and weight average (M_w) molecular weights, and the polydispersity index (PDI) of the polymer products were determined by gel permeation chromatography (GPC) with a FUTECS NS-4000 using a series of monodisperse polystyrene solutions as standards in 1,2,4-trichlorobenzene (HPLC grade) at 120°C . Cyclic voltammetry (CV) measurements were performed on an AMETEK Versa STAT 3 with a three-electrode cell system in a nitrogen bubbled $0.1 \text{ M } n\text{-Bu}_4\text{NPF}_6$ solution in acetonitrile at a scan rate of 100 mV s^{-1} at room temperature. An Ag/Ag^+ electrode, platinum wire, and platinum were used as the reference electrode, counter electrode, and working electrode,

respectively. The Ag/Ag^+ reference electrode was calibrated using a ferrocene/ferrocenium redox couple as an internal standard, whose oxidation potential is set at -4.8 eV with respect to a zero-vacuum level. The HOMO energy levels were obtained from the equation $\text{HOMO (eV)} = -(E_{\text{ox}}^{\text{onset}} - E_{\text{(ferrocene)}}^{\text{onset}} + 4.8)$. The LUMO levels were obtained from the equation $\text{LUMO (eV)} = -(E_{\text{(red)}}^{\text{onset}} - E_{\text{(ferrocene)}}^{\text{onset}} + 4.8)$. DFT calculations were performed using the Gaussian 09 package with the nonlocal hybrid Becke three-parameter Lee–Yang–Parr (B3LYP) function and the 6-31G basis set to investigate the HOMO and LUMO levels for the theoretically optimized geometries of the polymers.

Synthesis

3,6-Bis(5-bromopyridin-2-yl)-2,5-bis(5-decylheptadecyl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione (5PyDPP). 3,6-Bis(5-bromopyridin-2-yl)-2,5-dihydropyrrolo[3,4-c]pyrrole-1,4-dione (1.46 g, 3.26 mmol) and potassium carbonate (1.22 g, 8.81 mmol) were dissolved in 50 mL of *N,N*-dimethylformamide in a two-necked round flask under an argon atmosphere and the solution was heated at 110°C for 1 h. Then 5-decyl-1-bromoheptadecane (6 g, 13.05 mmol) was added slowly, and the mixture was refluxed overnight. After cooling to room temperature, the resulting mixture was quenched with water and extracted with dichloromethane. The organic layer was concentrated after drying over MgSO_4 . The crude product was purified by silica column chromatography using a solvent gradient mixture of 0–40% chloroform in hexane as the eluent to afford 1.79 g (yield 45.6%) of a fluffy purple solid as the product. ^1H NMR (400 MHz, CDCl_3): δ (ppm) 9.02 (d, $J = 8.5 \text{ Hz}$, 2H), 8.77 (d, $J = 2.3 \text{ Hz}$, 2H), 8.01 (dd, $J = 8.6, 2.4 \text{ Hz}$, 2H), 4.33–4.27 (t, $J = 8.0 \text{ Hz}$, 4H), 1.62 (d, $J = 7.7 \text{ Hz}$, 4H), 1.29–1.17 (m, 91H), 0.88 (t, $J = 6.7 \text{ Hz}$, 12H). ^{13}C NMR (100 MHz, CDCl_3): δ (ppm) 162.20, 150.26, 145.94, 144.69, 139.68, 128.53, 122.66, 111.44, 77.33, 77.01, 76.69, 42.82, 37.31, 33.57, 33.29, 31.94, 30.37, 30.18, 29.75, 29.74, 29.72, 29.68, 29.38, 26.68, 24.02, 22.71, 14.13.

MALDI-TOF MS (m/z) calcd: 1205.53. Found: 1205.85 (MH^+). Anal. calcd For $\text{C}_{70}\text{H}_{116}\text{Br}_2\text{N}_4\text{O}_2$: C, 69.74; H, 9.70; N, 4.65; found: C, 69.80; H, 9.78; N, 4.66.

Typical procedure for Stille polymerization and polymer purification

2PyDPP or 5PyDPP (100 μmol), **DSeBT** (100 μmol), tris(dibenzylideneacetone)dipalladium(0) ($\text{Pd}_2(\text{dba})_3$, 2.2 μmol) and tri-(*o*-tolyl)phosphine ($\text{P}(\text{o-tolyl})_3$, 9 μmol) were mixed in 10 mL of anhydrous chlorobenzene in a Schlenk flask and purged with argon for 30 min. Afterwards, the reaction mixture was refluxed for a certain period. After cooling down, the crude product was poured into 200 mL of methanol, and the precipitate was filtered and dried. The precipitate was subjected to sequential Soxhlet extraction with methanol, acetone, and hexane for a day for each step to remove the low molecular weight fractions of the material. The residue was extracted with chloroform to obtain the product after precipitating in methanol and drying *in vacuo*.

Synthesis of P1. Using the same procedure described above, a mixture of **2PyDPP** and **DSeBT** was used for polymerization,

and the solution was refluxed for 72 hours at 120 °C to give a dark blue powder. Isolated yield = 72%. $M_n = 44.8$ kDa, PDI = 2.87. ^1H NMR (400 MHz, CDCl_3): δ (ppm) 9.22–6.00 (br, 12H), 4.80–3.02 (br, 4H), 2.03–0.57 (br, 98H).

Synthesis of P2. Using the same procedure described above, a mixture of **5PyDPP** and **DSeBT** was used for polymerization, and the solution was refluxed for 5 hours at 100 °C to give a dark blue powder. Isolated yield = 44%. $M_n = 16.6$ kDa, PDI = 2.04. ^1H NMR (400 MHz, CDCl_3): δ (ppm) 9.36–5.52 (br, 12H), 4.81–3.07 (br, 4H), 1.83–0.67 (br, 110H).

Solubility tests

Each polymer solution at a known concentration was prepared and diluted to achieve solution absorbance spectra according to the concentration, and then the quantified solubility was obtained by comparing the λ_{max} of the spectra from 600 times (P1) or 400 times (P2) diluted saturated solution with the calibrated linear fit curves.

Thin-film microstructure analyses

Samples for thin-film microstructure analyses were prepared by spin-coating of polymer solutions (5 mg mL^{-1} in chlorobenzene at 2000 rpm for 60 s) on SiO_2/Si substrates. The atomic force microscopy (AFM) images of P1 and P2 were acquired by using an atomic force microscope (Digital Instruments Multimode IIIa) operated in tapping mode. Grazing incidence X-ray diffraction (GIXD) measurements were performed at the PLS-II 6D UNIST-PAL beamline of Pohang Accelerator Laboratory in Korea. The X-rays coming from the in-vacuum undulator (IVU) were monochromated ($E_k = 11.6$ keV and $\lambda = 1.069$ Å). The incidence angle of X-rays was adjusted to be in the range of 0.12° , which was close to the critical angle of samples. GIXD patterns were recorded by using a 2D CCD detector (SX165, Rayonix, USA). The detector was located at approximately 245 mm from the sample center. The raw data were processed and analyzed using the Igor-Pro software package.

Pole figure analysis

Pole figures for π - π stacking of the polymer films were plotted along the azimuthal angle χ . The profiles at $\chi = 0^\circ$ represent the peak intensity along the q_z direction, and those at $\chi = -90^\circ$ and $\chi = 90^\circ$ represent the peak intensity along the q_{xy} direction. The face-on and edge-on orientations are associated with the peaks in the regions of $0 \leq |\chi| \leq 35^\circ$ and $35 \leq |\chi| \leq 90^\circ$, respectively. The areas under the curve signify the population of the crystallites in each direction, and thus the relative population ratios of the crystallites can be verified by comparing the area ratios between the regions.

FET fabrication and measurement

OFET devices were fabricated using top gate/bottom-contact geometry (TG/BC). The source and drain contact electrodes (Ni/Al, 5 nm/15 nm) were patterned on glass substrates by thermal-evaporation deposition. The channel length was 20 μm and the channel width was 1000 μm . The glass substrates were then cleaned using deionized water, acetone and

isopropanol for 10 min each in a sonication bath followed by UV treatment for 30 min. P1 and P2 solutions in 5 mg mL^{-1} chlorobenzene (from Sigma Aldrich) were prepared by stirring at 80 °C overnight, spin-coated at 2000 rpm for 60 s on the patterned substrate, and then thermally annealed at three different temperatures (100, 200 and 300 °C) for 30 min. After cooling, polymethylmethacrylate (PMMA) solution in *n*-butyl acetate (80 mg mL^{-1} , Sigma Aldrich, $M_n = 120$ kDa, $C_i = 6.20 \text{ nF cm}^{-2}$) was deposited on the semiconducting layers as a gate dielectric at 2000 rpm for 60 s and then baked at 80 °C for 2 h in a N_2 -purged glove box. 50 nm of Al was thermally deposited as a gate material using a shadow mask in a thermal evaporator. The devices were characterized using a Keithley 4200-SCS semiconductor analyzer in a N_2 -filled glove box. The field-effect mobility (μ) and the threshold voltage (V_{th}) were derived in the saturation regime from the following equation:

$$I_D = \frac{W}{2L} C_i \mu (V_G - V_{\text{th}})^2$$

where I_D is the drain-source current, L is the channel length, W is the channel width, and C_i and V_G are the dielectric capacitance per unit area and the gate-source voltage, respectively.

Conflicts of interest

There are no conflicts to declare.

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